# VS-U5FH30BA60





FRED Pt<sup>®</sup> Gen 5 Ultrafast Single Phase Bridge, 600 V, 30 A

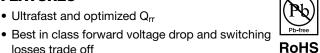


PRIMARY CHARACTERISTICS							
V <sub>R</sub>	600 V						
V <sub>F</sub> (typical) at 30 A, per diode	1.6 V						
t <sub>rr</sub> (typical) at 30 A, per diode	63 ns						
I <sub>O</sub> at T <sub>C</sub> = 131 °C	30 A						
Туре	Modules - diode, FRED Pt®						
Package	SOT-227						
Circuit configuration	Single phase bridge						

### **FEATURES**

losses trade off

Ultrafast and optimized Q<sub>rr</sub>



COMPLIANT

- · Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- Designed and gualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, the VS-U5FH30BA60 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V <sub>R</sub>		600	V			
Continuous forward current per diode	I <sub>F</sub>	T <sub>C</sub> = 105 °C	30	А			
Maximum power dissipation per diode	PD	T <sub>C</sub> = 105°C	53	W			
Maximum peak one cycle forward non- repetitive surge current	I <sub>FSM</sub>	10 ms or 6 ms rectangular pulse, $T_J = 25 \text{ °C}$ , no voltage reapplied	290 A				
		8.3 ms sine, $T_J = 25 \text{ °C}$ , no voltage reapplied					
Maximum I <sup>2</sup> t capability for fusing	l <sup>2</sup> t	No voltage reapplied, t = 10 ms	424				
Maximum - Capability for fusing	141	No voltage reapplied, t = 8.3 ms	387	A <sup>2</sup> s			
Maximum I <sup>2</sup> √t capability for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4244	A²√s			
RMS isolation voltage	VISOL	Any terminal to case, t = 1 min	2500	V			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			
SINGLE PHASE BRIDGE	•						
Maximum DC output current of bridge	lo	180° rect. conduction angle, T <sub>C</sub> = 131 °C	30	А			

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## Vishay Semiconductors

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage	V	I <sub>F</sub> = 30 A	-	1.6	2.1	V	
Forward voltage V <sub>FM</sub>		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.26	-		
		V <sub>R</sub> = 600 V	-	0.1	30		
Reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 600 V	-	14	-	μA	
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = 600 V	-	53	-		

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS	
Powerse receivery time	+	T <sub>J</sub> = 25 °C		-	57	-	ns A
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 30 A, di <sub>F</sub> /dt = 1000 A/μs, V <sub>R</sub> = 400 V	-	62	-	
Deale recover a current		T <sub>J</sub> = 25 °C		-	12	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	25	-	
	Q <sub>rr</sub>	T <sub>1</sub> = 25 °C	-	0.3	-		
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	0.9	-	μC
Junction capacitance	CT	V <sub>R</sub> = 600 V, f = 1 MHz		-	29	-	pF

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Single phase bridge - Thermal resistance junction to case, per diode	R <sub>thJC</sub>		-	-	1.39	°C/W	
Thermal resistance case to heatsink, per module	R <sub>thCS</sub>	Flat, greased, surface	-	0.05	-	C/W	
Weight			-	30	-	g	
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)	
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)	
Case style			SOT-227				

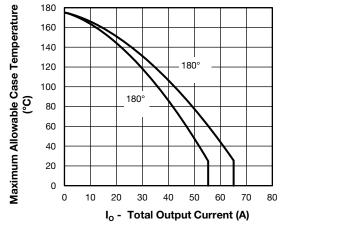


Fig. 1 - Current Rating Characteristics

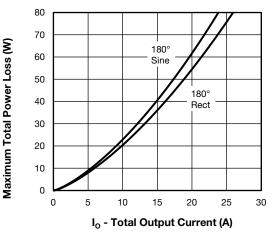


Fig. 2 - Total Power Loss Characteristics

Revision: 30-May-2022

2

Document Number: 96937

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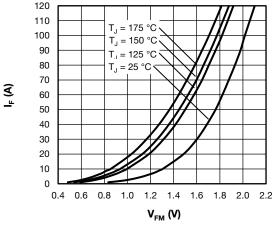


Fig. 3 - Typical Forward Voltage Drop Characteristics

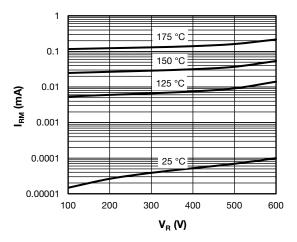
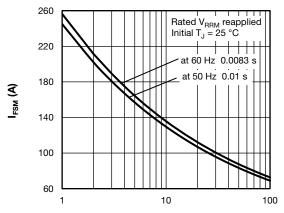


Fig. 4 - Typical Values of Reverse Current



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Non-Repetitive Peak Forward Surge Current vs. Number Pulses

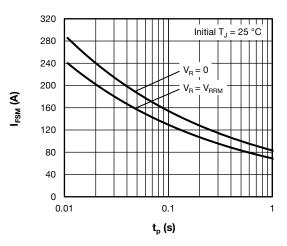


Fig. 6 - Non-Repetitive peak Forward Surge Current vs. Pulse Duration

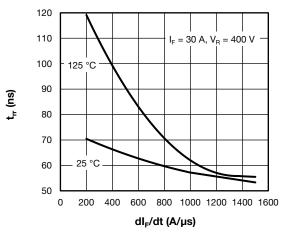


Fig. 7 - Diode Reverse Recovery Time vs. dl<sub>F</sub>dt

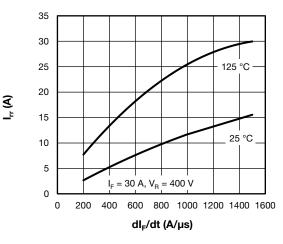


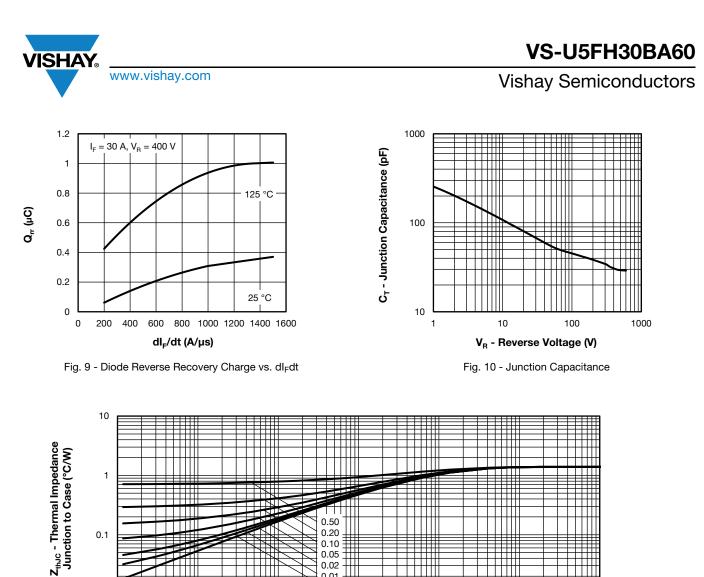
Fig. 8 - Diode Reverse Recovery Current vs. dI<sub>F</sub>dt

Revision: 30-May-2022

3

Document Number: 96937

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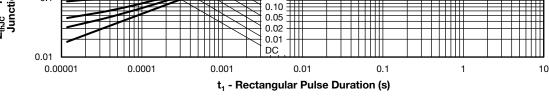


Fig. 11 - Maximum Thermal Impedance Junction to Case



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### **ORDERING INFORMATION TABLE**

Device code	vs-	U5F	н	30	В	Α	60
	1	2	3	4	5	6	7
	1 .	- Visł	nay Sem	niconduc	ctors pr	oduct	
	2 -	- U5F = Gen 5 FRED Pt <sup>®</sup> family					
	3 -	- H = Ultrafast FRED Pt <sup>®</sup> diode					
	4	- Current rating per module (30 = 30 A)					
	5 -	5 - B = circuit configuration (Single phase bridge)					
	6	Package indicator (SOT-227 standard insulated base					
	7	- Volt	tage rati	ng (60 =	= 600 V)		

CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Single phase bridge	В	4 (AC) 3 (-) $\downarrow$ (AC) 3 (-) $\downarrow$ (AC) 4 Lead Assignment 4 $\downarrow$ (AC) 3 (-) 1 (+) 2 (AC) 2 (AC) 2 (AC)				

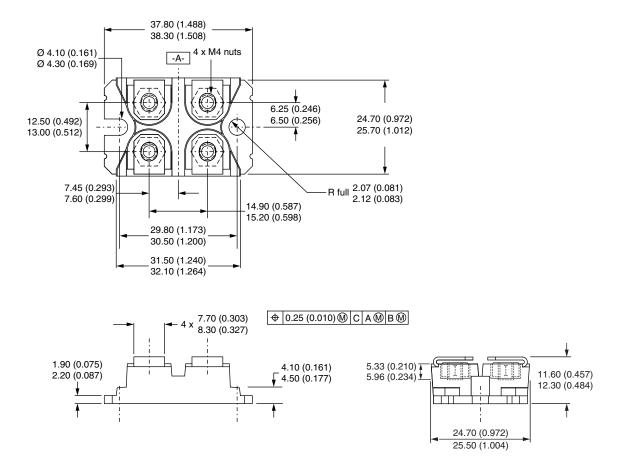
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95423					
Packaging information	www.vishay.com/doc?95425					

**Vishay Semiconductors** 



SOT-227 Generation 2

### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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